SPDT RF Switch SPDT RF Switch

M3SWA-2-50DRB+

Absorptive RF Switch with internal driver

The Big Deal

- High Isolation, 56 dB typ.
- High Input IP3, +46.5 dBm typ.
- Low insertion loss, 0.6 dB typ.
- Fast Rise/Fall time, 3.3 ns / 4.6 ns typ.
- Tiny Size, 3.25 x 3.25 x 0.9 mm



Product Overview

Mini-Circuits' M3SWA-2-50DRB+ is a MMIC SPDT absorptive switch with an internal driver designed for wideband operation from DC to 4.5 GHz supporting many applications requiring fast switching across a wide frequency range. This model provides excellent isolation, fast switching speed and high linearity in a tiny 3.25 x 3.25mm 8-Lead MCLP package.

Key Features

| Feature | Advantages |
|--|--|
| Wideband, DC to 4.5 GHz | One model can be used in many applications, saving component count. Also ideal for wideband applications such as military and instrumentation. |
| Absorptive switch | In the OFF condition, RF output ports which are not switched ON are terminated into 50Ω . This enables proper impedance termination of the circuitry following the RF output ports, preventing any unintended action such as oscillation. |
| High Isolation: • 62 dB at 1000 MHz • 35 dB at 4500 MHz | High isolation significantly reduces leakage of power into OFF ports. |
| High linearity: Input power at P1dB, 25.4 dBm typ. Input IP3, +46.5 dBm typ. | High linearity minimizes unwanted intermodulation products which are difficult or impossible to filter in multi-carrier environments such as CATV, or in the presence of strong interfering signal from adjacent circuitry or received by antenna. |
| Form-fit compatible with M3SWA-250DR+ | Fits into existing PCB footprint designed for M3SWA-2-50DR+ with minor electrical differences. |
| Tiny size, 3.25 x 3.25 mm MCLP package | Tiny footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB. |

50Ω DC - 4500 MHz

Absorptive RF Switch with internal driver

Product Features

- High Isolation, 56 dB typ.
- Low insertion loss, 0.6 dB typ.
- Fast Rise/Fall time, 3.3 ns / 4.6 ns typ.
- High Input IP3, +46.5 dBm typ.
- Replaces M3SWA-2-50DR+

Typical Applications

- Defense
- Communication Infrastructure
- Test and Measurements

M3SWA-2-50DRB+



CASE STYLE: DL805

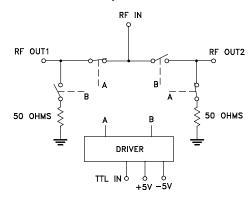
+RoHS Compliant

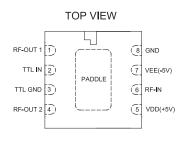
The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

General Description

M3SWA-2-50DRB+ is a high isolation fast switching absorptive GaAs PHEMT SPDT switch with an internal driver. It operates at +5V & -5V power supplies and has a single TLL compatible control port. It has been designed for wideband operation and packaged in a tiny 3.25mm x 3.25mm, 8-lead package.

Simplified Schematic and Pad Description





| Function | Pad Number | Description | |
|-----------------------|---------------|---|--|
| RF-IN | 6 | RF Common/ SUM port | |
| RF-OUT1 | 1 | RF Output port #1 | |
| RF-OUT2 | 4 | RF Output port #2 | |
| TTL IN | 2 | TTL Compatible Control Voltage Input | |
| TTL GND | 3 | TTL Ground | |
| V _{DD} (+5V) | 5 | Positive Supply Voltage V _{DD} | |
| V _{EE} (-5V) | 7 | Negative Supply Voltage V _{EE} | |
| GND | 8, paddle | Ground | |



RF Electrical Specifications¹, T_{AMB} =25°C, 50 Ω , V_{DD} = +5V, V_{EE} = -5V

| I AWIB / DI | | | | | |
|--|-----------------|------|------|------|-------|
| Parameter | Condition (MHz) | Min. | Тур. | Max. | Units |
| Frequency range ³ | | DC | | 4500 | MHz |
| | 10 - 100 | _ | 0.5 | 1.0 | |
| | 100 - 1000 | _ | 0.6 | 1.2 | |
| Insertion loss | 1000 - 2000 | _ | 0.6 | 1.4 | dB |
| | 2000 - 4000 | _ | 0.7 | 2.0 | |
| | 4000 - 4500 | _ | 1.4 | 2.5 | |
| | 10 - 100 | | 78 | | |
| | 100 - 1000 | | 59 | | |
| Isolation between Output Port 1 & 2 | 1000 - 2000 | | 49 | | dB |
| | 2000 - 4000 | | 39 | | |
| | 4000 - 4500 | | 32 | | |
| | 10 - 100 | 65 | 97 | _ | |
| | 100 - 1000 | 53 | 75 | _ | |
| Isolation between Common Port & Output Ports | 1000 - 2000 | 45 | 56 | _ | dB |
| | 2000 - 4000 | 30 | 43 | _ | |
| | 4000 - 4500 | 30 | 36 | _ | |
| | 10 - 100 | | 29 | | |
| | 100 - 1000 | | 30 | | |
| Input Return loss | 1000 - 2000 | | 27 | | dB |
| | 2000 - 4000 | | 23 | | |
| | 4000 - 4500 | | 22 | | |
| | 10 - 100 | | 29 | | |
| | 100 - 1000 | | 28 | | |
| Output Return loss (Both ON STATE & OFF STATE) | 1000 - 2000 | | 22 | | dB |
| (BOIL ON STATE & OLT STATE) | 2000 - 4000 | | 19 | | |
| | 4000 - 4500 | | 14 | | |
| | 10 - 100 | | 19.2 | | |
| | 100 - 1000 | | 24.5 | | |
| Input Power at P1dB ² | 1000 - 2000 | | 25.4 | | dBm |
| | 2000 - 4000 | | 25.0 | | |
| | 4000 - 4500 | | 23.8 | | |
| | 10 - 100 | | 39.7 | | |
| L LIDO | 100 - 1000 | | 44.7 | | |
| Input IP3 (Paut-0 dPm/Tana) | 1000 - 2000 | | 46.5 | | dBm |
| (Pout=0 dBm/Tone) | 2000 - 4000 | | 44.0 | | |
| | 4000 - 4500 | | 40.1 | | |
| Thermal Resistance - Junction-to-ground lead at 85°C stage temperature | | | 34.2 | | °C/W |

DC Electrical Specifications

| Parameter | Min. | Тур. | Max. | Units |
|--|-------|------|-------|-------|
| Positive Supply Voltage, V _{DD} | 4.75 | 5 | 5.25 | V |
| Negative Supply voltage, V _{EE} | -5.25 | -5 | -4.75 | V |
| Positive Supply Current, I _{DD} | _ | 5 | 9 | mA |
| Negative Supply Current, I _{EE} | -9 | -3 | _ | mA |
| Control Voltage Low | _ | 0 | 0.8 | V |
| Control Voltage High | 2.1 | 2.3 | 5 | V |
| Control Current Low | _ | 0 | 0.2 | mA |
| Control Current High | _ | 0.4 | 5 | mA |

- 1. Tested on Mini-Circuits' test board TB-M3SWA250DRB+ (See Fig.1)
- Input Power at P1dB compression drops to 13 dB at 10 MHz.
 All RF-ports must be DC blocked or held at 0V DC.

Switching Specifications

| Parameter | Condition | Min. | Тур. | Max. | Units |
|---------------------------------|---------------------------------------|------|------|------|-------|
| ON Time, 50% control to 90% RF | DE D: 0 ID | | 14.4 | | ns |
| OFF Time, 50% control to 10% RF | RF Pin= 0 dBm RF Freg.= 500 MHz | | 11.3 | | ns |
| Video Leakage | Control Freq.= 500 KHz | | 42.5 | | mV |
| Rise Time, 10% RF to 90% RF | Control High= 2.3V Control Low= 0V | | 3.3 | | ns |
| Fall Time, 90% RF to 10% RF | Control Low = 0 V | | 4.6 | | ns |



Absolute Maximum Ratings⁴

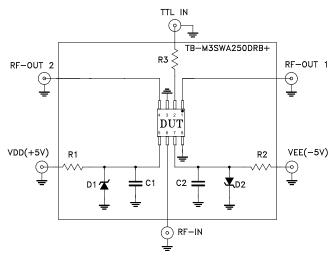
| Parameter | Ratings | |
|-------------------------|-----------------|--|
| Operating temperature | -55°C to +100°C | |
| Storage temperature | -55°C to +100°C | |
| RF Input power | +24 dBm | |
| Junction Temperature | 134°C | |
| Total Power Dissipation | 0.4W | |
| DC Voltage, Pin 5 | +6V | |
| DC Voltage, Pin 7 | -6V | |

Permanent damage may occur if any of these limits are exceeded. Electrical Maximum ratings are not intended for continuous normal operation.

Truth Table

| State of Control Voltage | RF-IN to RF-OUT1 | RF-IN to RF-OUT 2 |
|--------------------------|------------------|-------------------|
| LOW | ON | OFF |
| HIGH | OFF | ON |

Characterization & Application Circuit



| Component | Size | Value | P/N | Manufacturer |
|-----------|-----------|-----------|-----------------|------------------|
| DUT | 3.25x3.25 | N/A | M3SWA-2-50DRB+ | MCL |
| D1, D2 | SOD-123 | Vz = 5.6V | MMSZ4690T1G | ON Semiconductor |
| R1, R2 | 0603 | 11.5Ω | RK73H1JTTD11R5F | KOA |
| R3 | 0603 | 100Ω | RK73H1JTTD1000F | KOA |
| C1, C2 | 0603 | 10pF | 06031A100GAT2A | AVX |

Note: D1&D2 are optional.

Figure 1. Characterization & Application Circuit

Note: (DUT soldered on Mini-Circuits Characterization & Application Test Board TB-M3SWA250DRB+). Insertion Loss, Amplitude Unbalance, Isolation, Return Loss, Input Power at 1dB Compression (P1dB) & Input IP3 tested using E5071C microwave network analyzer.

- Condition:
- 1. Insertion Loss, Amplitude Unbalance, Isolation & Return Loss: Pin = 0dBm
- 2. Input IP3(IIP3):Two tones, spaced 1 MHz apart, 0dBm/tone output.

Product Marking



Marking may contain other features or characters for internal lot control



Additional Detailed Technical Information

additional information is available on our dash board.

| Porformana Data | Data Table | |
|---------------------------------------|---|--|
| Performance Data | Swept Graphs | |
| Case Style | DL805 Plastic package, exposed paddle, lead finish=Matte-Tin | |
| Tape & Reel | F58 | |
| Standard quantities available on reel | 7" reels with 1000 devices 13" reels with 2000, 4000 devices | |
| Suggested Layout for PCB Design | PL-120 | |
| Evaluation Board | TB-M3SWA250DRB+ | |
| Environmental Ratings | ENV16 | |

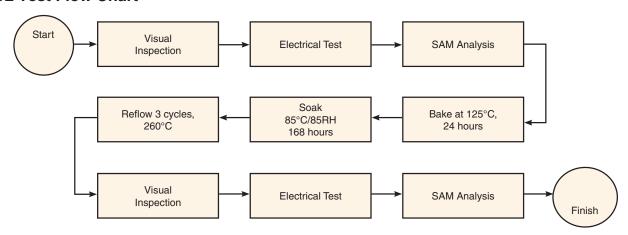
ESD Rating

Human Body Model (HBM): Class 0 (Pass 100V) in accordance with ESD STM5.1-2001

MSL Rating

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL Test Flow Chart



Additional Notes

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the Standard Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp

